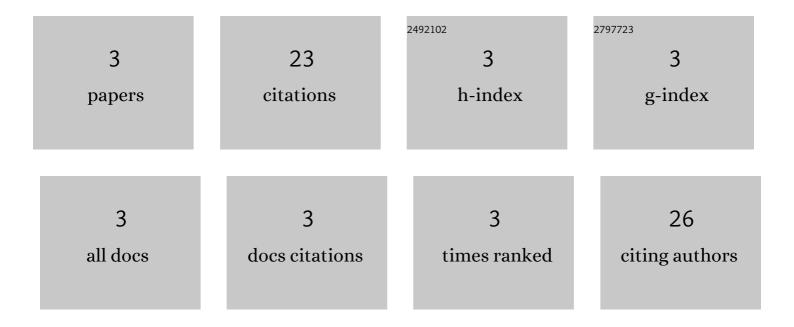
## Asafuji Ryosuke

List of Publications by Year in descending order

Source: https://exaly.com/author-pdf/6642552/publications.pdf Version: 2024-02-01



#	Article	IF	CITATIONS
1	Generation of stacking faults in 4H-SiC epilayer induced by oxidation. Materials Research Express, 2018, 5, 015903.	0.8	4
2	Photoluminescence study of oxidation-induced faults in 4H-SiC epilayers. AIP Advances, 2015, 5, .	0.6	8
3	Si and C emission into the oxide layer during the oxidation of silicon carbide and its influence on the oxidation rate. AIP Advances, 2015, 5, .	0.6	11